

# 2SB903/2SD1212

# 30V/12A High-Speed Switching Applications

### **Applications**

 Suitable for relay drivers, high-speed inverters, converters, and other general large-current switching applications.

#### **Features**

- $\cdot$  Low collector-to-emitter saturation voltage : V\_CE(sat)=(-)0.5V (PNP), 0.4V (NPN) max.
- · Large current capacity.

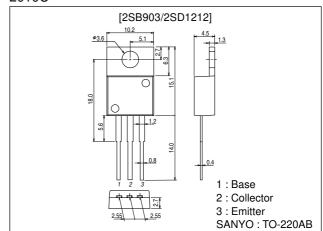
():2SB903

# **Specifications**

### **Absolute Maximum Ratings** at Ta = 25°C

## **Package Dimensions**

unit:mm 2010C



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(–)60	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(–)30	٧
Emitter-to-Base Voltage	V <sub>EBO</sub>		(–)6	٧
Collector Current	lc		(–)12	Α
Collector Current (Pulse)	I <sub>CP</sub>		(–)20	Α
Collector Dissipation	PC		1.75	W
Collector Dissipation		Tc=25°C	35	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Farameter	Symbol		min	typ	max	Offic
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(-)0.1	mA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(-)0.1	mA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)1A	70*		280*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)6A	30			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)1A		120		MHz

<sup>\*:</sup> The 2SB903/2SD1212 are graded as follows by h<sub>FE</sub> at 1A:

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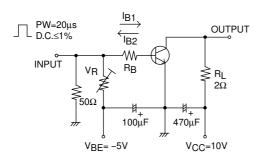
Rank	Q	R	S		
hFE	70 to 140	100 to 200	140 to 280		

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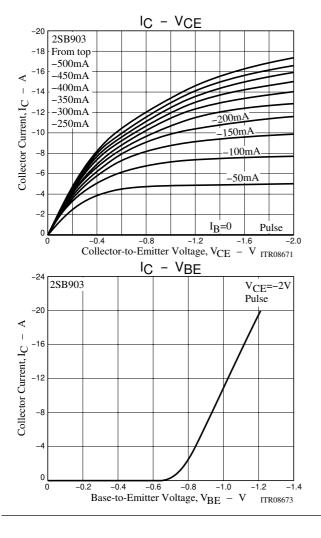
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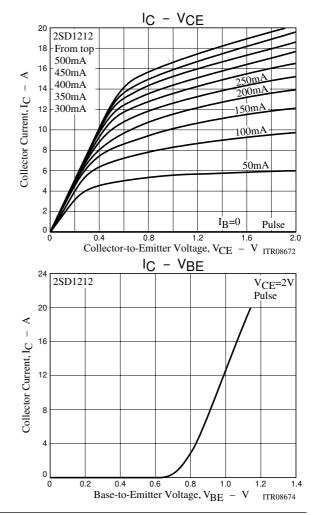
Parameter	Symbol	Conditions	Ratings			Unit
raiametei	Symbol		min	typ	max	
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)5A, I <sub>B</sub> =(-)0.25A			(-0.5)	V
Collector-to-Enfitter Saturation Voltage					0.4	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)1mA, I <sub>E</sub> =0	(-)60			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =(–)1mA, R <sub>BE</sub> =∞	(-)30			٧
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =(-)1mA, I <sub>C</sub> =0	(-)6			٧
Turn-ON Time	ton	See specified Test Circuit		(0.1)		μs
Turn-ON Time				0.2		μs
Storage Time	t <sub>stg</sub>	See specified Test Circuit		(0.3)		μs
				0.5		μs
Fall Time	t <sub>f</sub>	See specified Test Circuit		0.03		μs

### **Switching Time Test Circuit**

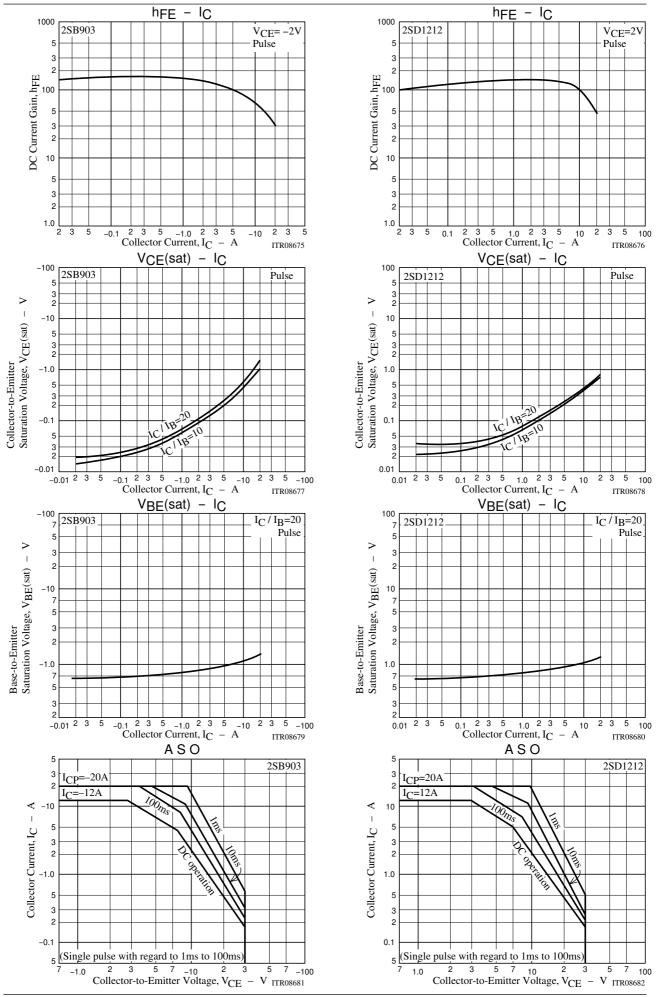


IC=10IB1= -10IB2=5A (For PNP, the polarity is reversed.)

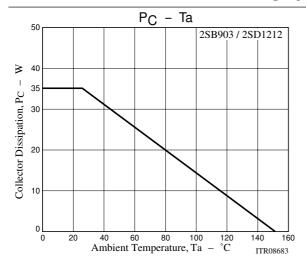




### 2SB903/2SD1212



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